

PRODUCT/PROCESS CHANGE NOTIFICATION

PCN MMS-MIC/08/3771 Notification Date 06/17/2008

Silicon change for 32K devices of STM32 family

MIC - MICROCONTROLLERS

Table 1. Change Implementation Schedule

Forecasted implementation date for change	30-Jun-2008
Forecasted availabillity date of samples for customer	10-Jun-2008
Forecasted date for STMicroelectronics change Qualification Plan results availability	30-Jun-2008
Estimated date of changed product first shipment	10-Sep-2008

Table 2. Change Identification

Product Identification (Product Family/Commercial Product)	See page 7
Type of change	Product design change
Reason for change	Power consumption improvement
Description of the change	We have improved the power consumption of all our STM32 products with a 32 KB Flash memory (both Access and Performance Lines). This makes the STM32 family even better suited to power-sensitive applications. Please refer to the tables on pages 5 to 7 for further details concerning this improvement in the different operating modes (Run and Low-power). As a result of this change, new orderable part numbers have been created that will replace the currently ordered part numbers (see page 7).
Product Line(s) and/or Part Number(s)	See attached
Description of the Qualification Plan	See attached
Change Product Identification	Part number ends with "A"
Manufacturing Location(s)	

Table 3. List of Attachments

Customer Part numbers list	
Qualification Plan results	

Customer Acknowledgement of Receipt	PCN MMS-MIC/08/3771
Please sign and return to STMicroelectronics Sales Office	Notification Date 06/17/2008
Qualification Plan Denied	Name:
Qualification Plan Approved	Title:
	Company:
🗖 Change Denied	Date:
Change Approved	Signature:
Remark	

Name	Function
Colonna, Daniel	Division Marketing Manager
Nicholas, Jimmy Edward	Division Product Manager
Narche, Pascal	Division Q.A. Manager

DOCUMENT APPROVAL

				Max[1]					
Symbol Parameter		Conditions	f _{HCLK}	Be	fore	А	Unit		
				T _A = 85 °C	T _A = 105 °C	T _A = 85 °C	T _A = 105 °C		
			72 MHz	50	50.3	45	46		
		External	48 MHz	36.1	36.2	32	33		
		clock[2], all	36 MHz	28.6	28.7	26	27		
	Supply I _{DD} current in Run mode P	peripherals enabled	24 MHz	19.9	20.1	18	19	1	
			16 MHz	14.7	14.9	13	14		
			8 MHz	8.6	8.9	7	8	mA	
I DD				72 MHz	32.8	32.9	30	31	ШA
		External clock[2], all	48 MHz	24.4	24.5	23	24		
			36 MHz	19.8	19.9	19	19.5		
			24 MHz	13.9	14.2	13	14	1	
		disabled	16 MHz	10.7	11	10	11		
			8 MHz	6.8	7.1	6	7		

Maximum current consumption in Run mode, code with data processing running from Flash

[1]Data based on characterization results, not tested in production.

[2]External clock is 8 MHz and PLL is on when fHCLK > 8 MHz; external clock is 9 MHz for fHCLK = 36 MHz.

Maximum current consumption in Sleep mode, code running from Flash or RAM

					М	ax		
Symbol Parameter		Conditions	f _{HCLK}	Be	fore	After		Unit
	-			T _A = 85 °C[3]	T _A = 105 °C[2]	T _A = 85 °C[3]	T _A = 105 °C[2]	
			72 MHz	30	32	26	27	
		External	48 MHz	20	20.5	17	18	
		clock[1], all	36 MHz	15.5	16	14	15	
		peripherals enabled	24 MHz	11.5	12	10	11	
	Cummbu		16 MHz	8.5	9	7	8	
I _{DD}	Supply current in		8 MHz	5.5	6	4	5	mA
עטי		Sleep mode	72 MHz	7.5	8	7.5	8	ШA
	•	External	48 MHz	6	6.5	6	6.5	
		clock[1], all	36 MHz	5	5.5	5	5.5	
		peripherals	24 MHz	4.5	5	4.5	5	
		disabled 16 M	16 MHz	4	4.5	4	4.5	
			8 MHz	3	4	3	4	

[1]External clock is 8 MHz and PLL is on when fHCLK > 8 MHz; external clock is 9 MHz for fHCLK = 36 MHz.

[2]Data based on characterization results, tested in production at VDD max, fHCLK max. and TA max.

[3]Based on characterization, not tested in production.

				Ma	ax		
Symbol	Parameter	Conditions	Be	fore	Af	Unit	
			T _A = 85 °C[2]	T _A = 105 °C[1]	T _A =85°C[2]		T _A =105°C[1]
Supply	Supply current in	Regulator in Run mode, low- speed and high-speed internal RC oscillators and high-speed oscillator OFF (no independent watchdog)	200	370	160	200	
I _{DD}	Stop mode	Regulator in Low Power mode, low-speed and high- speed internal RC oscillators and high-speed oscillator OFF (no independent watchdog)	180	340	145	185	μA
	Supply current in Standby mode[3]	Low-speed internal RC oscillator and independent watchdog OFF, low-speed oscillator and RTC OFF	3.2	4.5	3.2	4.5	
I _{DD_VBAT}	Backup domain supply current	Low-speed oscillator and RTC ON	1.9	2.2[2]	1.9	2.2[2]	

[1]Data based on characterization results, tested in production at V_{DDmax} , f_{HCLK} max. and T_A max.

[2]Based on characterization, not tested in production.

[3]To have the Standby consumption with RTC ON, add I_{DD_VBAT} (Low-speed oscillator and RTC ON) to I_{DD} Standby (when V_{DD} is present the Backup Domain is powered by V_{DD} supply).

					o[1]		
Symbol	Parameter Conditions			ore V _{DD} / V _{BAT} = 3.3V	Af V _{DD} / V _{BAT} = 2.4V	ter V _{DD} / V _{BAT} = 3.3V	Unit
	Supply current in	Regulator in Run mode, low- speed and high-speed internal RC oscillators and high-speed oscillator OFF (no independent watchdog)	23.5	24	23.5	24	
I _{DD}	Stop mode	Regulator in Low Power mode, low-speed and high- speed internal RC oscillators and high-speed oscillator OFF (no independent watchdog)	13.5	14	13.5	14	μΑ
	Supply current in Standby mode[2]		1.7	2	1.7	2	
I _{DD_VBAT}	Backup domain supply current	Low-speed oscillator and RTC ON	1.1	1.4	1.1	1.4	

Typical current consumptions in Stop and Standby modes (32 KB Flash capacity)

[1]Typical values are measured at T_{A} = 25 °C, V_{DD} = 3.3 V, unless otherwise specified.

[2]To have the Standby consumption with RTC ON, add I_{DD_VBAT} (Low-speed oscillator and RTC ON) to I_{DD} Standby (when V_{DD} is present the Backup Domain is powered by V_{DD} supply).

Part number summary

Old part number	New Part number	Memory size	Package	Line
STM32F103R6T6	STM32F103R6T6A	32K	LQFP64	Performance
STM32F101R6T6	STM32F101R6T6A	32K	LQFP64	Access
STM32F103C6T6	STM32F103C6T6A	32K	LQFP48	Performance
STM32F101C6T6	STM32F101C6T6A	32K	LQFP48	Access
STM32F103T6U6	STM32F103T6U6A	32K	QFN36	Performance
STM32F101T6U6	STM32F101T6U6A	32K	QFN36	Access



--- ST Internal ---

Reliability Qualification Plan

New Product Little Piranha

General Information			Locations		
Product Line	CORTEX		Wafer fab location	WF3 / 0.18µm	
Product Description	Little Piranha - Die 412		Assembly plant location	Malta- Muar- Carsem	
Commercial Product	STM32				
Product division	MMS MCD				
Package Description	TQFP64 - TQFP48 - QFN 36				

The Quality of a product is built-in during the design, material procurement, manufacturing, testing and screening.

The reliability tests are performed to assess the integrity of product subjected to extreme physical and electrical conditions.

They guarantee the product reliability during the end-application manufacturing and operation.

The methodology for product approval will be performed in accordance to STMicroelectronics standard operating procedures (SOP).



--- ST Internal ---

1.1 Qualification plan

Qualification type	Derivative product / Derivative NVM		
NPR ref	NPR412		
Device name	412		
Test vehicle	STM32F103		
Package	TQFP64 - TQFP48 - QFN 36		
Assembly site	MALTA - MUAR - CARSEM		
Process type	018MMEMBF/2P5M		
Diffusion site	WF3		
Test site	Rousset -AngMoKio (EWS) / Malta-Muar (FINAL TEST)		

Lot ref:	Qualification type:	Start qual	
	Product		
1	TQFP64 – 12 parts for ESD HBM-CDM/LU TQFP48 – 3 parts for ESD CDM QFN36 – 3 parts for ESD CDM	April 08	May 08
1	TQFP64- 77 Plastic finish good for HTOL168h	June 08	June 08

1.2 Reliability Trials

The following tests will be performed in order to check the reliability performances.

1.2.1 DIE ORIENTED TESTS

TEST	METHOD	CONDITION	Duration Qualification (<i>Monitoring</i>)	Sampling Size / lot
ESD Human Body Model(HBM)	ADCS0060102 JESD22 A114	1500 Ω, 100 pF 2 Kv	NA	3
Charge Device Model(CDM)	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	750V on corner pins, 500V on others		3/ package
Latch up (LU)	ADCS 0018695	T= 105°C	NA	6
Early Life Failure Rate (ELFR) High Temperature Operating Life Test (HTOL)=	JESD74 (Q100-008)	140°C, 3.6V	24 hrs/168hrs	77

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